Siliconix DG5043

# **Monolithic General Purpose CMOS Analog Switch**

### **Features**

- ±15-V Input Range
- On-Resistance:  $<50 \Omega$
- Break-Before-Make Switching
- TTL and CMOS Compatible

### **Benefits**

- Improved Signal Headroom
- Reduced Switching Errors
- No Shorting of Inputs
- Simple Interfacing

### **Applications**

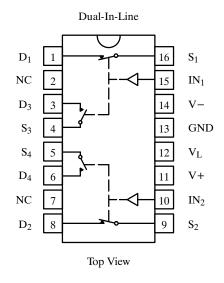
- Audio Switching
- Instrumentation
- Battery Powered Systems

# **Description**

The DG5043 solid state analog switch is recommended for general purpose applications in instrumentation, and process control. Built on the Siliconix PLUS-40 high voltage CMOS process, this device provides ease-of-use and performance advantages to the system designer. Key performance features of the DG5043 are 1-µs switching,

low power supply requirements, and break-before-make switching. Each switch conducts equally well in either direction, when on, and blocks up to 30 V peak-to-peak when off. Off leakage current is 1-nA maximum. An epitaxial layer prevents latch up. For new designs, DG403 is recommended.

# **Functional Block Diagram and Pin Configuration**



#### **Truth Table**

Logic	SW <sub>1</sub> , SW <sub>2</sub>	SW <sub>3</sub> , SW <sub>4</sub>
0	OFF	ON
1	ON	OFF

 $\begin{array}{rl} Logic \ "0" = & \leq 0.8 \ V \\ Logic \ "1" = & \geq 2 \ V \\ Switches shown for Logic \ "1" input. \end{array}$ 

#### **Ordering Information**

Temp Range	Package	Part Number		
0 to 70°C	16-Pin Plastic DIP	DG5043CJ		

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# **Absolute Maximum Ratings**

V+ to V
GND to V
$V_L$ (GND - 0.3 V) to 44 V
Digital Inputs $^a$ $V_S$ , $V_D$ $(V-)$ $-2$ $V$ to $(V+$ plus $2$ $V)$ or $30$ mA, whichever occurs first
Current (Any Terminal) Continuous
Current, S or D (Pulsed 1 ms 10% duty) 100 mA
Storage Temperature –65 to 125°C

Power Dissipation (Package) <sup>b</sup>	
16-Pin Plastic DIP <sup>c</sup>	пW

#### Notes:

- a. Signals on  $S_X$ ,  $D_X$ , or  $IN_X$  exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC Board.
- c. Derate 6 mW/°C above 75°C

# **Specifications**

		Test Conditions Unless Otherwise Specified		C Suffix 0 to 70°C			
Parameter	Symbol	V+=15  V, V-=-15  V $V_L=5 \text{ V}, V_{IN}=2 \text{ V}, 0.8 \text{ V}^e$	Temp <sup>a</sup>	Min <sup>c</sup>	Typ <sup>b</sup>	Max <sup>c</sup>	Unit
Analog Switch							
Analog Signal Range <sup>d</sup>	V <sub>ANALOG</sub>		Full	-15		15	V
Drain-Source On-Resistance	r <sub>DS(on)</sub>	$I_{S} = -10 \text{ mA}, V_{D} = \pm 10 \text{ V}$	Room Full			50 75	Ω
Switch Off Leakage Current	į.	$V_S = V_D = 14 \text{ V}$	Room Full	$-1 \\ -100$		1 100	nA
	$I_{S(off)}$	$V_{S} = V_{D} = -14 \text{ V}$	Room Full	-1 -100		1 100	
Channel On Leakage Current	I <sub>D(on)</sub>	$V_S = V_D = 14 \text{ V}$	Room Full			2 200	
		$V_{S} = V_{D} = -14 \text{ V}$	Room Full	$-2 \\ -200$			
Digital Control							
Input Current with V <sub>IN</sub> Low	$I_{ m IL}$	$V_{IN}$ Under Test = 0.8 V	Full	-1		1	
Input Current with V <sub>IN</sub> High	$I_{\mathrm{IH}}$	V <sub>IN</sub> Under Test = 2 V	Full	-1		1	μA
<b>Dynamic Characteristics</b>							
Turn-On Time	t <sub>ON</sub>	$V_S = \pm 10 \text{ V}, R_L = 1 \text{ k}\Omega, C_L = 35 \text{ pF}$ See Figure 1	Room			1200	
Turn-Off Time	t <sub>OFF</sub>	See Figure 1	Room			700	ns
Charge Injection <sup>d</sup>	Q	$C_{L} = 10 \text{ nF}, V_{gen} = 0 \text{ V}, R_{gen} = 0 \Omega$	Room		30		рC
Off Isolation <sup>d</sup>	OIRR	$R_L = 75 \Omega, C_L = 5 \text{ pF, f} = 1 \text{ MHz}$	Room		75		dB
Crosstalk (Channel-to-Channel)d	X <sub>TALK</sub>	$R_L = 75 \Omega, V_S = 2 V_{P-B} f = 1 MHz$	Room		89		
Source Off Capacitance	$C_{S(off)}$		Room		15		pF
Drain Off Capacitance <sup>d</sup>	$C_{D(off)}$	$V_D = V_S = 0 \text{ V}, f = 1 \text{ MHz}$	Room		17		
Channel On Capacitance <sup>d</sup>	$C_{D(on)}$		Room		45		
Power Supplies							
Positive Supply Current	I+	$V_{IN} = 0$ or 2.4 V	Full			300	
Negative Supply Current	I-		Full	-300			
Logic Supply Current	$I_{L}$	$V_{\rm IN} = 0$ or 2.4 V	Full			300	μA
Ground Current	$I_{GND}$		Full	-300			

#### Notes

- a. Room =  $25^{\circ}$ C, Full = as determined by the operating temperature suffix.
- b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- d. Guaranteed by design, not subject to production test.
- $V_{IN}$  = input voltage to perform proper function.

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## **Test Circuits**

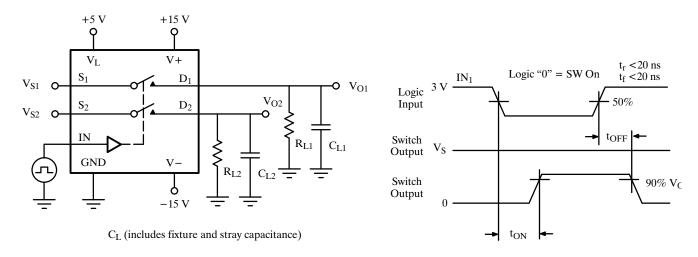


Figure 1. Switching Time

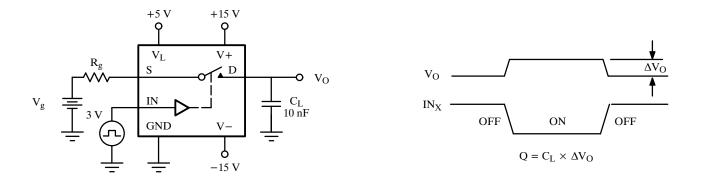


Figure 2. Charge Injection